# Low Voltage, Dual DPDT in miniQFN16 

## DESCRIPTION

The DG2599 is a CMOS Dual DPDT (Dual Double Pole Double Throw) analog switch that operates over a wide voltage range of 1.65 V to 5 V . It is optimized for portable applications switching audio, SIM card signals, and other low power signals.
The DG2599 features low ON resistance of 2.8 W at 3 V power supply, fast switching speed, and low power consumption even when control logic signals are below $\mathrm{V}_{+}$ power supply voltage. The well matched dual DPDT switches conduct signals equally in both directions. The DG2599 is designed to guarantee break before make switching.
As a committed partner to the community and the environment, Vishay Siliconix manufactures this product with lead (Pb)-free device terminations. DG2599 are offered in a miniQFN package. The miniQFN package has a nickel palladium- gold device termination and is represented by the lead (Pb)-free "-E4" suffix. The nickel-palladium-gold device terminations meet all JEDEC ${ }^{\circledR}$ standards for reflow and MSL ratings.

## FEATURES

- Halogen-free according to IEC 61249-2-21 definition


RoHS COMPLANT halogen FREE

- Power off protection on COM1 and COM2 pins
- Latch up current great than 300 mA per JESD78
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912


## APPLICATIONS

- Cellular phones
- PMPs and PDAs
- Modems and peripherals
- Computers and ebooks
- Tablet devices
- Displays and gaming
- STB

| ORDERING INFORMATION |  |
| :--- | :---: |
| PART NUMBER | PACKAGE |
| DG2599DN-T1-GE4 | miniQFN16 $1.8 \mathrm{~mm} \times 2.6 \mathrm{~mm}$ |



## TRUTH TABLE (DG2599)

| LOGIC | NC1, 2, 3 AND 4 | NO 1, 2, 3 AND 4 |
| :---: | :---: | :---: |
| 0 | ON | OFF |
| 1 | OFF | ON |

Device Marking: $\underline{A} x x$ xx = Date/Lot Traceability Code


Note: Pin 1 has long lead

DG2599

| PARAMETER |  | SYMBOL | LIMIT | UNIT |
| :---: | :---: | :---: | :---: | :---: |
| Reference to GND | V+ |  | -0.3 to +6 | V |
|  | IN, COM, NC, $\mathrm{NO}^{\text {a }}$ |  | -0.3 to (V++0.3) |  |
| Current (any terminal except NO, NC or COM) |  |  | 30 | mA |
| Continuous current (NO, NC, or COM) |  |  | $\pm 300$ |  |
| Peak current (pulsed at $1 \mathrm{~ms}, 10 \%$ duty cycle) |  |  | $\pm 500$ |  |
| Storage temperature (D suffix) |  |  | -65 to +150 | C |
| Package solder reflow conditions ${ }^{\text {d }}$ | miniQFN16 |  | 250 |  |
| Power dissipation (packages) ${ }^{\text {b }}$ | miniQFN16 ${ }^{\text {c }}$ |  | 525 | mW |

## Note

a. Signals on NC, NO, or COM or IN exceeding V+ will be clamped by internal diodes. Limit forward diode current to maximum current ratings
b. All leads welded or soldered to PC board
c. Derate $6.6 \mathrm{~mW} /{ }^{\circ} \mathrm{C}$ above $70^{\circ} \mathrm{C}$
d. Manual soldering with iron is not recommended for leadless components. The miniQFN-16 is a leadless package. The end of the lead terminal is exposed copper (not plated) as a result of the singulation process in manufacturing. A solder fillet at the exposed copper lip cannot be guaranteed and is not required to ensure adequate bottom side solder interconnection

| ELECTRICAL CHARACTERISTICS (V+ = 3 V ) |  |  |  |  |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| PARAMETER | TEST CONDITIONS | TEMP. | MIN. | TYP. | MAX. | UNIT |
| Power Supply and Signal |  |  |  |  |  |  |
| V+ supply voltage |  | Full | 1.65 | - | 5.5 | V |
| V+ supply current | $\mathrm{V}_{\text {IN }}=0$ or $\mathrm{V}+$ | Full | - | 0.001 | 2 | $\mu \mathrm{A}$ |
| Analog signal range |  | Full | 0 | - | V+ | V |
| Switch On-Resistance and Leakage |  |  |  |  |  |  |
| Drain-source on-resistance | $\mathrm{V}+=3 \mathrm{~V}, \mathrm{I}_{\mathrm{NO} / \mathrm{NC}}=100 \mathrm{~mA}, \mathrm{~V}_{\mathrm{COM}}=0.9 \mathrm{~V}, 2.3 \mathrm{~V}$ | Room | - | 2.8 | 3.3 | W |
|  |  | Full | - | - | 3.6 |  |
| On-resistance flatness | $\mathrm{V}_{+}=3 \mathrm{~V}, \mathrm{I}_{\mathrm{NO} / \mathrm{NC}}=100 \mathrm{~mA}, \mathrm{~V}_{\text {COM }}=0$ to $\mathrm{V}+$ | Room | - | 0.24 | 1.1 |  |
|  |  | Full | - | - | 1.3 |  |
| Switch off leakage current | $\mathrm{V}+=4.3 \mathrm{~V}, \mathrm{~V}_{\mathrm{NO} / \mathrm{NC}}=0.3 \mathrm{~V} / 4 \mathrm{~V}, \mathrm{~V}_{\mathrm{COM}}=4 \mathrm{~V} / 0.3 \mathrm{~V}$ | Room | -10 | 0.1 | 10 | nA |
|  |  | Full | -100 | - | 100 |  |
| Channel on-leakage current | $\mathrm{V}_{+}=4.3 \mathrm{~V}, \mathrm{~V}_{\mathrm{NO} / \mathrm{NC}}$ and $\mathrm{V}_{\text {COM }}=0.3 \mathrm{~V} / 4 \mathrm{~V}$ | Room | -10 | 0.1 | 10 |  |
|  |  | Full | -100 | - | 100 |  |
| Digital Control |  |  |  |  |  |  |
| Input, high voltage | $\mathrm{V}+=4.3 \mathrm{~V}$ | Full | 1.6 | - | - | V |
|  | $\mathrm{V}+=3 \mathrm{~V}$ |  | 1.3 | - | - |  |
| Input, low voltage | $\mathrm{V}+=4.3 \mathrm{~V}$ | Full | - | - | 0.6 |  |
|  | $\mathrm{V}+=3 \mathrm{~V}$ |  | - | - | 0.5 |  |
| Input, bias current | $\mathrm{V}_{\text {IN }}=\mathrm{V}+$ | Full | -1 | 0.01 | 1 | $\mu \mathrm{A}$ |
| Dynamic Characteristics |  |  |  |  |  |  |
| Turn on-time | $\mathrm{V}_{\text {COM }}$ or $\mathrm{V}_{\mathrm{NO} / \mathrm{NC}}=3 \mathrm{~V}, \mathrm{R}_{\mathrm{L}}=50 \Omega, \mathrm{C}_{\mathrm{L}}=35 \mathrm{pF}$ | Room | - | - | 90 | ns |
|  |  | Full | - | - | 115 |  |
| Turn off-time | $\mathrm{V}_{\text {COM }}$ or $\mathrm{V}_{\mathrm{NO} / \mathrm{NC}}=3 \mathrm{~V}, \mathrm{R}_{\mathrm{L}}=50 \Omega, \mathrm{C}_{\mathrm{L}}=35 \mathrm{pF}$ | Room | - | - | 70 |  |
|  |  | Full | - | - | 85 |  |
| Break before make time | $\mathrm{V}_{\text {COM }}$ or $\mathrm{V}_{\text {NO/NC }}=3 \mathrm{~V}, \mathrm{R}_{\mathrm{L}}=50 \Omega, \mathrm{C}_{\mathrm{L}}=35 \mathrm{pF}$ | Room | 2 | - | - |  |
|  |  | Full | 2 | - | - |  |
| Charge injection | $\mathrm{C}_{\mathrm{L}}=1 \mathrm{nF}, \mathrm{R}_{\mathrm{GEN}}=0 \Omega$ | Room | - | $\pm 10$ | - | pC |
| Off isolation | $\mathrm{R}_{\mathrm{L}}=50 \Omega, \mathrm{C}_{\mathrm{L}}=5 \mathrm{pF}, \mathrm{f}=1 \mathrm{MHz}$ |  | - | -66 | - | dB |
| Crosstalk | $\begin{gathered} \mathrm{R}_{\mathrm{L}}=50 \Omega, \mathrm{C}_{\mathrm{L}}=5 \mathrm{pF}, \mathrm{f}=1 \mathrm{MHz}, \\ \text { non-adjacent channels } \end{gathered}$ |  | - | -110 | - |  |
| 3 dB bandwith | $\mathrm{C}_{\mathrm{L}}=5 \mathrm{pF}, \mathrm{R}_{\mathrm{L}}=50 \Omega$ |  | - | 186 | - | MHz |

# ELECTRICAL CHARACTERISTICS (V+ = 3 V) 

| PARAMETER | TEST CONDITIONS | TEMP. | MIN. | TYP. | MAX. | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Source off capacitance | $\mathrm{V}_{\text {IN }}=0$ or $\mathrm{V}+$, $\mathrm{f}=1 \mathrm{MHz}$ |  | - | 9 | - | pF |
| Channel on capacitance | $\mathrm{V}_{\text {IN }}=0$ or $\mathrm{V}+, \mathrm{f}=1 \mathrm{MHz}$ |  | - | 26 | - |  |

TYPICAL CHARACTERISTICS $\left(\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}\right.$, unless otherwise noted)

$R_{\text {ON }}$ vs. $V_{\text {COM }}$ and Single Supply Voltage


Ron vs. Analog Voltage and Temperature


Supply Current vs. Temperature


Ron $_{\text {on }}$ vs. Analog Voltage and Temperature

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Ron vs. Analog Voltage and Temperature


Leakage Current vs. Temperature

TYPICAL CHARACTERISTICS $\left(\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}\right.$, unless otherwise noted)


Leakage vs. Analog Voltage

(NC) Switching Time vs. Temperature

(NO) Switching Time vs. Temperature


## Insertion Loss, Off Isolation and Crosstalk



Switching Threshold vs. Supply Voltage

## TEST CIRCUITS



Break-Before-Make Interval


IN depends on switch configuration: input polarity determined by sense of switch.

## Charge Injection

## TEST CIRCUITS



Off-Isolation


Channel Off / On Capacitance

Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see www.vishay.com/ppg?67667.

Package Information

## Thin miniQFN16 Case Outline



Top view


Bottom view


| DIMENSIONS | MILLIMETERS ${ }^{(1)}$ |  |  | INCHES |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  | MIN. | NOM. | MAX. | MIN. | NOM. | MAX. |
| A | 0.50 | 0.55 | 0.60 | 0.020 | 0.022 | 0.024 |
| A1 | 0 | - | 0.05 | 0 | - | 0.002 |
| A3 | $0.15 \text { ref. }$ |  |  | $0.006 \text { ref. }$ |  |  |
| b | 0.15 | 0.20 | 0.25 | 0.006 | 0.008 | 0.010 |
| D | 2.50 | 2.60 | 2.70 | 0.098 | 0.102 | 0.106 |
| e | 0.40 BSC |  |  | 0.016 BSC |  |  |
| E | 1.70 | 1.80 | 1.90 | 0.067 | 0.071 | 0.075 |
| L | 0.35 | 0.40 | 0.45 | 0.014 | 0.016 | 0.018 |
| L1 | 0.45 | 0.50 | 0.55 | 0.018 | 0.020 | 0.022 |
| $\mathrm{N}^{(3)}$ | 16 |  |  | 16 |  |  |
| $\mathrm{Nd}{ }^{(3)}$ | 4 |  |  | 4 |  |  |
| $\mathrm{Ne}{ }^{(3)}$ | 4 |  |  | 4 |  |  |

## Notes

${ }^{(1)}$ Use millimeters as the primary measurement.
${ }^{(2)}$ Dimensioning and tolerances conform to ASME Y14.5M. - 1994.
${ }^{(3)} \mathrm{N}$ is the number of terminals. Nd and Ne is the number of terminals in each D and E site respectively.
(4) Dimensions b applies to plated terminal and is measured between 0.15 mm and 0.30 mm from terminal tip.
${ }^{(5)}$ The pin 1 identifier must be existed on the top surface of the package by using identification mark or other feature of package body.
${ }^{(6)}$ Package warpage max. 0.05 mm .

## ECN: T16-0226-Rev. B, 09-May-16

DWG: 6023

## RECOMMENDED MINIMUM PADS FOR MINI QFN 16L



Mounting Footprint
Dimensions in mm (inch)

## Disclaimer

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